Steric Crowding in Tetrel Bonds

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ABSTRACT
The tetravalent character of tetrel atoms leaves only limited room for an incoming nucleophile to approach and engage in a noncovalent bond with a tetrel atom. Any such approach can only occur at the expense of internal geometric distortions. The balance between attractive forces and repulsive steric crowding was studied for a series of Lewis acids of the type FTR₃ (T=Si, Ge, Sn, Pb) which were allowed to interact with various bases. The strength and other properties of the tetrel bond are examined as the R groups are made progressively larger, varying from H and CH₃ to isopropyl and t-butyl, which induce steric crowding with the incoming base. The effects of crowding which impede the bond can be offset by enlarging the T atom, by adding electron-withdrawing substituents to the Lewis acid, or by considering stronger bases such as anions. The tetrel bond energies reach up to 10 kcal/mol for a pair of neutral molecules with no electron-withdrawing substituents on the Lewis acid. Adding -CF₃ substituents grows the interaction energy to as high as 35 kcal/mol, and a further increment occurs for an anionic base, taking the maximum up to 54 kcal/mol.
1. INTRODUCTION

Analogous to the venerable and thoroughly studied H-bond\textsuperscript{1-3}, it is now well accepted that the bridging proton can be replaced by any of a litany of larger atoms, without compromising the strength of the interaction\textsuperscript{4-7}. These substitute atoms are typically electronegative ones, drawn from the right side of the periodic table. Unlike the H atom which is partially positive within the context of a covalent O-H or N-H bond, the substitute atom’s electronegativity leaves it with an overall partial negative charge, which would ordinarily tend to repel any incoming nucleophilic basic molecule. However, the negative charge around the substitute atom X is far from uniform, but is rather quite anisotropic. There is commonly a region of positive electrostatic potential, directly opposite the R-X covalent bond, which is surrounded by the expected negative areas. These positive regions are widely denoted as $\sigma$-holes, due to their origin and location, directly opposite the R-X $\sigma$-bond\textsuperscript{8-10}. It is this $\sigma$-hole which can attract a nucleophile in their initial long range encounter. As the two molecules are drawn together, the interaction incorporates other attractive forces, most notably charge transfer and dispersion.

Depending on the identity of the atom replacing the bridging proton, and more particularly its familial nomenclature, these interactions are generally referred to as halogen, chalcogen, and pnicogen bonds. These noncovalent bonds have been intensively studied in the last years, leading to a number of general conclusions that are common to all\textsuperscript{11-28}. In the first place, substituent effects markedly enhance the strength of the bond as electron-withdrawing substituents are placed on the electron-accepting Lewis acid molecule. As one moves down a column of the periodic table, e.g. Cl → Br → I the pertinent atom becomes both less electronegative and more polarizable, all factors which contribute to a stronger bond. There is a reluctance of first-row atoms F, O, and N to participate as electron acceptors in these bonds, although they can be persuaded to do so by, for example, adding strongly electron-withdrawing substituents, as in NFH\textsubscript{2} which, unlike NH\textsubscript{3}, will engage in a pnicogen bond\textsuperscript{29}.

These ideas have recently been extended one column to the left in the periodic table from the pnicogens, to include the tetrel family of atoms. Although the current moniker of a tetrel bond was coined fairly recently\textsuperscript{30}, evidence of their presence goes back some years earlier. Early calculations\textsuperscript{31} documented the ability of both SiH\textsubscript{4} and SiF\textsubscript{4} to form such a bond with NH\textsubscript{3}, which was confirmed by rotational spectra\textsuperscript{32}. Free-jet IR spectroscopy\textsuperscript{33} suggested that such a bond can form between SiF\textsubscript{4} and either N\textsubscript{2} or CO, despite the weakness of the latter bases. The idea of a tetrel bond was also invoked in an experimental study\textsuperscript{34} of a reaction mechanism, which went on to suggest this bond becomes weaker as the size of the tetrel atom gets smaller, an idea that has been echoed since\textsuperscript{35-36}. It is accepted\textsuperscript{37-38} that like the other related noncovalent bonds, the tetrel bond is also strengthened as more electron-withdrawing substituents are added to the Lewis acid\textsuperscript{39-40}, as in the case of SiF\textsubscript{4}, or if the Lewis acid bears a positive charge\textsuperscript{41-42}, or likewise in the case of an anionic base\textsuperscript{43}. 

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Tetrel bonds can appear within the intramolecular context of a single molecule as in 1-methylsilatranne or trifluorosilylhydrazines. The concept has been broadened to include a variety of Lewis bases, such as radicals, anions, carbenes, or π-systems. There are also indications that an incipient tetrel bond is a prime ingredient in the idea of S_N2 chemical reactions, or in biological processes, and in the formation of metal-organic frameworks. Tetrel bonds are not necessarily limited to σ-hole interactions where a nucleophile approaches directly opposite a covalent bond, but can also involve π-holes which lie out of the molecular plane. The study of these interactions has proliferated quite a bit in the last few years, which has included examination of the way tetrel bonds can be strengthened via cooperative effects.

There is one essential factor concerning tetrel bonds which makes them rather different from their related noncovalent cousins. Taking the halogen bond as an example, the approaching nucleophile is separated by 180° from the R group that is covalently attached to the halogen atom. Things get only a little more crowded for the chalcogen and pnicogen atoms. In the case that the R_2Z molecule (Z=pnicogen) is trigonal pyramidal in shape, a nucleophile could still approach the central Z atom without incurring substantial steric repulsion with the R groups, separated from them by as much as 109°. But the situation becomes more crowded for tetrel atoms. With roughly tetrahedral spacing of its four substituents, a nucleophile would be separated from the R groups by something on the order of 70°. In order to reduce the destabilizing effects of the associated steric repulsions, the Lewis acid would probably need to undergo a good deal of angular deformation, which would introduce its own energetic cost.

So the issue of steric crowding is a highly important one for tetrel bonds, but nonetheless one which has been scarcely studied. This issue is of special importance as tetrel bonds show evidence of being the strongest of the entire family of related noncovalent interactions. It is the purpose of the current work to thoroughly analyze the effects that steric repulsions can have upon such bonds, and their ability to form at all. In an effort to do so, tetrel atoms T varying in size from Si to Ge, Sn, and Pb are considered as the central atom in FTR_3 Lewis acids, so as to consider how tetrel atom size relates to crowding effects. (C was not considered as its tetrel bonds are quite weak.) Starting with H as the group attached to T, this substituent is progressively enlarged to methyl, and thence to the bulkier isopropyl and t-butyl groups. The restriction to alkyl groups reduces any differences in electron-withdrawing power of the substituents, keeping the focus on purely steric factors. But at the same time, the ability of electron-withdrawing substituents to enhance the tetrel bond strength is considered, separately from steric effects, by comparing CF_3 to CH_3 as R groups, as well as considering halogen atoms of varying size and electron-withdrawing power as alternate substituents. The power of stronger nucleophiles to potentially overcome the inhibiting effects of possibly crippling steric crowding is evaluated by replacing the neutral NH_3 base by various anions.
2. SYSTEMS AND METHODS

The unsubstituted TH$_4$ molecules (T=Si, Ge, Sn, Pb) were each taken as a starting point Lewis acid; one H atom was replaced by F so as to provide a reasonably strong σ-hole opposite this F atom in FTH$_3$, with which a base can interact. The possibility of steric crowding was introduced in stages, replacing each of the three H atoms first by CH$_3$, and then by isopropyl and t-butyl. In order to consider the ability of electron-withdrawing substituents on the tetrel atom to overcome steric crowding, a number of CF$_3$ groups were placed on the T, as well as halogen atoms of varying size. NH$_3$ was employed as the primary electron donor, due to its simplicity, containing a single lone pair and with no π bonds that might complicate the analysis. A larger, and more crowded NMe$_3$ base was considered as well, as were the highly nucleophilic F$^-$ and Br$^-$ anions. In each case, the base was initially positioned directly opposite the F atom of FTR$_3$ and the entire geometry of the complex fully optimized.

Quantum calculations were carried out via the Gaussian-09 program. MP2 was used in order to account for electron correlation. The aug-cc-pVDZ basis set was applied to all atoms with the exception of Sn and Pb which were represented by the aug-cc-pVDZ-PP pseudopotential from the EMSL library which accounts for relativistic effects. This level of theory has demonstrated its accuracy and effectiveness in numerous previous studies of related systems.

All geometries were fully optimized, and checked to ensure they were true minima by frequency calculations. The binding energy, $\Delta E$, was defined as the difference between the energy of the complex and the sum of the energies of the optimized monomers. This quantity was corrected by the counterpoise procedure to remove basis set superposition error. The interaction energy of each dimer differs in that it involves the energies of the monomers within the context of their geometry within the dimer. As such, this quantity represents the interaction between two monomers that have already been deformed into the structures they will ultimately adopt within the dimer. Thus, the binding and interaction energies differ by the strain or deformation energy of each monomer that takes it from its optimized structure to that within the dimer.

Molecular electrostatic potentials surrounding each molecule were visualized via the Chemcraft program and quantified by the Multiwfn program to locate its maxima and minima on the isodensity surface corresponding to $\rho=0.001$ au. Charge transfer was evaluated by the Natural Bond Orbital (NBO) technique. The AIM formalism elucidated bond paths through analysis of the topology of the electron density, making use of the AIMALL program.

3. RESULTS

3.1 T=Si

As the smallest of the four tetrel atoms considered here, one might expect Si to suffer from the largest degree of steric crowding. The geometries of various FSiR$_3$···NH$_3$ equilibrium structures are pictured in Fig 1,
and their salient characteristics summarized in Table 1. There is little evidence of substantial steric repulsion in the FSiH₃···NH₃ complexes where the N is able to approach within 2.56 Å of the Si atom. The binding energy is 5.49 kcal/mol, which is fairly large, comparable to that in the classically H-bonded water dimer. Despite the nearly unimpeded approach of the two molecules, the formation of this complex induces a certain amount of strain in the FSiH₃ molecule, amounting to 1.93 kcal/mol. Much of this deformation energy arises from the bending back of the H atoms away from the approaching nucleophile, with the θ(FHN) angle dropping by 5° from 107.7° in the monomer to 102.8° within the complex.

When the 3 H atoms are enlarged to methyl groups, a new dynamic emerges. The larger CH₃ is associated with a certain degree of steric repulsion with the NH₃. But there is also the possibility that H-bonds can be formed from an H atom of each methyl group to the N. And these H-bonds are favored by a longer intermolecular separation which permits them to be less distorted from linearity. Another factor in this change is the electron-releasing property of the methyl groups. As may be seen in the first two rows of Table 2, the substitution of the three H atoms of FSiH₃ by methyls reduces the maximum in the electrostatic potential at the σ-hole from 41 to 27 kcal/mol. This decrease reduces the force pulling the N atom in toward the Si, permitting the CH··N H-bonds to better take hold. Consequently the R(Si··N) distance is much longer at 3.75 Å. The binding energy of 2.24 kcal/mol can be attributed more to the three CH··N H-bonds and less to a tetrel bond (see below).

One can counter the electron-releasing ability of the three methyl groups by replacing one or more of them with CF₃ which ought to have an opposite effect. And indeed, Table 2 shows that each such substitution enhances the σ-hole magnitude by 3-7 kcal/mol. It is thus no surprise to see that the tetrel bond is now able to overcome the CH··N HBs, and bring the N atom progressively closer. R(Si··N) diminishes from 3.75 Å for FSiMe₃ down to 2.39, 2.21, and 2.12 Å as each such substitution is put in place. With this contraction comes a growing binding energy, from 2.11 kcal/mol for a single CF₃ group up to 18.2 kcal/mol when all three are exchanged. The strength of this bond is reflected also in the contracting intermolecular distance, a scant 2.12 Å for the trisubstituted Lewis acid. Note that this closer proximity comes with a price in the form of growing distortion energy of the Lewis acid, rising all the way up to 17.3 kcal/mol for FSi(CF₃)₃. The binding energy of 18.2 kcal/mol thus comes at the expense of this large deformation energy, so must reflect quite a strong attractive force. Indeed, when the deformation energies are accounted for, the final column of Table 1 shows that the interaction energy in the FSi(CF₃)₃···NH₃ complex is more than 35 kcal/mol, quite a strong interaction. This quantity is enlarged by some 10-11 kcal for each CH₃ to CF₃ substitution, reflecting the sensitivity of the tetrel bond to the electron-withdrawing capacity of the latter group.

A further enlargement of the R groups to isopropyl (Iso) makes it more difficult for the NH₃ base to approach the Si. There is a minimum that occurs for R=3.091 Å. Similar to the trimethyl case, the tetrel bond
is reinforced by several CH··N HBs. Because of the long intermolecular distance, the binding energy is rather small, and is in fact very slightly repulsive (ΔE= +0.2 kcal/mol) when counterpoise corrections are included. There is a small distortion energy which makes the interaction energy between the pre-deformed monomers attractive, by 2.3 kcal/mol.

Interestingly, for the tri-isopropyl case, one sees a competition of sorts between two possibilities. If the isopropyl groups are rotated a bit, one can generate a second minimum, with a much closer approach of the Si and N atoms, R= 2.50 Å. However, this second minimum is higher in energy than the first, by some 6 kcal/mol. Due to the much closer proximity of the two molecules, there is a correspondingly higher distortion energy of 14.2 kcal/mol. Thus the interaction energy in the last column of Table 1 shows a larger interaction energy for this contracted dimer, 7.4 vs 2.3 kcal/mol for the more stable conformation. In other words, the steric repulsions present in certain tetrel bonding situations can lead in some cases to either i) a long and weak tetrel bond, perhaps reinforced by secondary HBs or ii) a short but stronger tetrel bond which must overcome strong internal deformations and may result in a positive overall value of ΔE.

As a final point, one can again strengthen the interaction by introduction of an electron-withdrawing CF$_3$ group. As may be seen in Table 2, the inclusion of only a single such group ramps V$_{s,\text{max}}$ up from 9.9 to 23.1 kcal/mol. This powerful σ-hole pulls the NH$_3$ in toward the Si to a distance of only 2.38 Å, and eliminates any secondary minimum at a longer separation. The small binding energy of only 2.7 kcal/mol masks a large distortion energy of 10.3 kcal/mol which leads to an interaction energy of 13.0 kcal/mol, quite similar to the case where a single Me group is replaced by CF$_3$.

The replacement of each of the three isopropyl groups by the still larger tert-butyl (Tb) groups, can be anticipated to add a higher degree of steric hindrance. Nonetheless, the N atom can still approach within 2.52 Å of the central Si atom. However, the repulsion is reflected in the positive ΔE, +10.8 kcal/mol. As the two molecules pull one another together, the three t-butyl groups must move apart to make room for the approaching ligand. As may be seen in the next column of Table 1, the strain induced in the FSiTb$_3$ molecule amounts to 17.4 kcal/mol. When this deformation energy is taken into account, the interaction energy between the two monomers in the complex, once they have appropriately distorted, is attractive and equal to -6.6 kcal/mol. Due to the positive value of ΔE, it was thought that perhaps there might be a second minimum with a longer intermolecular separation, as was observed for FSiIso$_3$. However, no such minimum was found. It might be noted that the properties of V$_{s,\text{max}}$ for FSiTb$_3$ are unlike most of the Lewis acids in Table 2 (see below).

Rather than incorporation of alkyl groups of increasing size, another means of introducing steric repulsions into the Lewis acids is the replacement of the three H atoms of FSiH$_3$ by halogen atoms of increasing size. Although such substitutions also introduce the possibility that NH···X HBs can compete with the desired FSi··N tetrel bond, the equilibrium geometry of FSiX$_3$ ···NH$_3$ is characterized by a linear FSi··N tetrel bond for X=Cl,
Br, and I, as exhibited in Figs 2a, 2b, and 2c, respectively. The binding energies for these three trihalogenated Lewis acids diminish from 5.5 to 3.3 kcal/mol as the halogen is enlarged and gets progressively less electron-withdrawing, as may be seen in the last three rows of Table 1. The R(Si··N) tetrel bond lengths are rather short, around 2.1 Å for these three halogen substitutions, suggesting any detrimental effects from steric repulsions are overshadowed by the stronger tetrel bonds connected with the electron-withdrawing halogen substituents. The close approach of the two monomers does in fact lead to very substantial monomer deformation energies, between 15 and 20 kcal/mol. When corrected by these distortions, the interaction energies are quite large, ranging between 18 kcal/mol for FSiI$_3$ up to 25 kcal/mol for FSiCl$_3$. So even though these halogenated Lewis acids incur quite large monomer deformation energies, their attraction toward the base outweighs this crowding effect. It might be added parenthetically, that the situation is quite different when Si is replaced by the smaller C atom. The weakness of any C··N tetrel bond is easily overwhelmed by the NH··X HBs, which are in fact observed in the equilibrium geometries for X=Cl and Br.

### 3.1.1 Analysis of Wave Functions

Some further insights into the nature of the binding within these complexes can be gleaned from Table 2. The first column displays the maximum in the molecular electrostatic potential (MEP) of each Lewis acid monomer, on the $\rho=0.001$ au isodensity surface, which corresponds to the $\sigma$-hole position, viz. directly opposite the F atom. This quantity is fairly large, 41.0 kcal/mol for the unsubstituted SiH$_3$. As noted in the second column of Table 2, this point lies 1.940 Å away from the Si atom. The replacement of the three H atoms by electron-releasing methyl groups lowers $V_{s,max}$ by 34%, down to 26.9 kcal/mol, while also displacing it 0.2 Å further away from the central Si atom. This drop in $V_{s,max}$ can be recovered by replacing each methyl group by the electron-withdrawing CF$_3$, with each such substitution providing a boost of roughly 5 kcal/mol, as indicated earlier.

The addition of larger isopropyl (Iso) groups adds an interesting wrinkle. It was noted in Table 1 that there are two minima for the FSiIsO$_3$···NH$_3$ complex, with R differing by 0.5 Å. The two structures differ in the orientations of the isopropyl groups. If these groups are situated as they are in the slightly more stable structure a, with the longer R, the maximum in the MEP is 22.0 kcal/mol, and lies 2.24 Å from Si. But the reorientation of the isopropyl groups which permits the closer approach of the NH$_3$ pulls this point 0.8 Å further away from Si, and drops its value to less than half, at 9.9 kcal/mol. The replacement of one of these Iso groups by CF$_3$ eliminates the second, and more distant, maximum in the MEP, and raises the value of $V_{s,max}$ back up over 20 kcal/mol. The value of this maximum for FSiTb$_3$ is similar to structure a for FSiIsO$_3$, while lying further away from Si.

The values of $V_{s,max}$ for the three FSiX$_3$ monomers in the last three rows of Table 2 are quite sensitive to the nature of the halogen. The most electron-withdrawing Cl substituents yield a value of 27.0 kcal/mol, which is
reduced to half that amount for FSiI₃. This point moves progressively further from the central Si atom as the X atom becomes larger, out to 2.41 Å for FSiI₃. It might be interesting to note that even with these three electron-withdrawing substituents, Vₛ,max remains lower than for the unsubstituted FSiH₃, and generally lower than FSiMe₃, despite the weakness of the tetrel bonds involving the latter two monomers. Indeed, FSiI₃ has a Vₛ,max that is as low as any of the other acids considered here. This observation contrasts with the rather high interaction energies of the FSiX₃ acids.

One can obtain an alternate view of the strength of the intermolecular interaction via AIM analysis of the topography of the electron density of each complex. In particular, the density at the bond critical point connecting a pair of atoms is thought to be directly related to the strength of the noncovalent bond 25, 95-105. This quantity is reported as ρ_{BCP} in Table 2. So for example, the density at this point is equal to 0.0233 au in the bond connecting Si with N in the FSiH₃···NH₃ heterodimer, as displayed in the first row. When the three H atoms of FSiH₃ are replaced by methyl groups, the bond path between Si and N disappears, and is replaced by three such paths, each connecting N with one H atom of each methyl group. It is for this reason that the R(Si··N) distance is so long in this complex, as noted in Table 1. The Si··N bond path reappears when one of the methyl groups is replaced by CF₃, with ρ=0.0325 au. This bond is augmented by a weaker bond between N and one of the F atoms of the CF₃ group. The latter bond is not present in the dimers containing two and three CF₃ groups, and ρ_{BCP} grows continuously with each such replacement, up to 0.055 au for the trisubstituted species. This increase in the AIM quantity is mirrored in the binding energy ΔE, and even more so in the interaction energy.

There are two minima for the FSiIsO₃ complex. The AIM data for the more stable of the two, structure a, reflects the long R(Si··N) distance in that there is no bond path between these two atoms. Instead, the complex is held together by three N···H H-bonds, one to each isopropyl group, and a C···N bond which might be characterized as a tetrel bond to one C of an isopropyl group. It is thus not surprising that this complex is only weakly bound. The electron-withdrawing capacity of a CF₃ group, when substituted for one isopropyl re-establishes the Si···N tetrel bond, in addition to providing a negative value of ΔE. This bond is elongated and weakened, for the tri-t-butyl derivative, and ΔE becomes positive once again, with ρ_{BCP} dipping to 0.0264 au. The largest of all the values of ρ_{BCP} are associated with the halogenated FSiX₃ acids in the last three rows of Table 2.

NBO offers a means of examining charge transfers, in particular those between individual orbitals, as an alternate window into the nature of intermolecular interactions. In most cases of bonds of the tetrel type examined here, the chief intermolecular transfer takes charge from the N lone pair into the σ*(Si-F) antibonding orbital. These quantities are reported in the penultimate column of Table 2 and show that there are other interorbital transfers that contribute to the interaction. In the FSiH₃···NH₃ complex for example, the Si-F
transfer perturbation energy E(2) of 17.97 kcal/mol is supplemented by transfers of 3.90 kcal/mol into each of
the three Si-H antibonding orbitals. Hence while AIM would attribute the binding here to be solely due to the
Si···N tetrel bond, NBO would assign a substantial contribution from three SiH···N H-bonds. The situation
changes for FSiMe₃···NH₃ where AIM finds no evidence of a tetrel bond, whereas NBO again identifies not
only the three CH···N H-bonds characterized by AIM, but also a weak tetrel bond. Indeed, NBO finds there is a
tetrel bond in all cases, even in the long Si···N bond in FSiIsoc₃···NH₃, where again AIM fails to locate a tetrel
bond. It is characteristic of the NBO interpretation to find multiple sources of bonding. For example, the tetrel
bond in FSiMe(CF₃)₂···NH₃ is augmented by transfer of charge from the N lone pair to all three of the σ*(Si-C)
antibonds even though these orbitals do not point directly to the N, but which add nonetheless to the Si···N tetrel
bond strength. These same subsidiary transfers to antibonds not directly opposite the N atom are in fact
contributing factors to the tetrel bonds of all Lewis acids. The transfer into the σ*(SiF) antibonding orbital is
rather large, ~20 kcal/mol, for the halogenated FSiX₃ complexes. These contributions are supplemented by
three secondary transfers, into each of the SiX antibonds, of nearly equal magnitude.

As there is a significant amount of charge that is being placed into the antibonding SiF orbital, one would
expect to see a weakening and consequent lengthening of this bond. Such a stretch is indeed observed, as
displayed in the last column of Table 2. The amount of this elongation varies from 0.005 Å for the weak tetrel
bond involving FSiMe₃ to a maximum of 0.042 Å for FSi(CF₃)₃ which is associated with the strongest Si tetrel
bond of all those considered.

Summarizing the competition between attractive tetrel bonding and steric repulsions as substituents are
placed on the Si, FSiH₃ is unimpeded so can form a fairly strong tetrel bond with NH₃. The replacement of H
by methyl groups induces a certain amount of steric hindrance, which is compensated to some degree by the
formation of three CH···N HBs, although they cannot fully make up for the loss of the tetrel bond. The NH₃ is
drawn in despite any steric repulsions as one or more methyl groups are replaced by the much more electron-
withdrawing CF₃, which amplifies the Si σ-hole. The interaction is exothermic, even though formation of the
complex must overcome monomer deformation energies between 11 and 17 kcal/mol. In contrast, when the
methyls are replaced by the larger isopropyl groups, the ensuing steric repulsions lead to an endothermic
complexation. There is a fine balance observed between an attractive tetrel bond and steric repulsion, which
leads to the presence of more than one minimum. One structure keeps the Si and N atoms 3.09 Å apart, and
another permits a closer association of 2.50 Å but at the expense of a high monomer deformation energy. The
same steric problems lead to an endothermic complexation, despite an attractive tetrel bond and a negative
interaction energy, when the isopropyl groups are replaced by the even bulkier t-butyl. Although the FSiX₃
Lewis acids suffer from substantial monomer deformation, the attraction is strong enough to pull the base in to
short intermolecular contact distance, and an exothermic ∆E.
3.2 Heavier Tetrel Atoms

Given the observation that the Si atom has difficulty in accommodating a tetrel bond while covalently attached to certain bulky groups, it would be interesting to see how some of the heavier tetrel atoms might fare in this regard. One might expect that their larger size might expand the space around them, pushing the bulky groups further away, and perhaps better make room for an incoming Lewis base. There should also be a greater attractive force, based on the idea that along with larger atomic size will come lesser electronegativity and higher polarizability, both factors that should enhance the intensity of a σ-hole.

The ability of the heavier tetrel atoms to enable noncovalent bonding to a NH₃ molecule is summarized in Table 3, and their full geometries illustrated in Fig 3. FGeH₃ is nearly unimpeded, allowing the N to approach within 2.63 Å, only 0.07 Å longer than in the case of the Si analogue, as evident in Fig 3a. The binding energy of -5.8 kcal/mol is slightly stronger than for the lighter Si analogue. And the heavier molecule suffers a 0.5 kcal/mol lesser distortion energy. As in the Si case, the replacement of H atoms by methyl groups in Fig 3b again reduces the binding energy, but with the difference that the N atom is not pushed as far from Ge as it is from Si, approaching to within 2.78 Å. Enlargement of the substituents to isopropyl groups in Fig 3c does not lead to the same steric problems for the larger Ge: The NH₃ approaches to within 2.82 Å, without a second, more distant, minimum, and the binding energy is clearly exothermic. Note also that the deformation energy of FGeIso₃ is only 2.4 kcal/mol in this complex, as compared to more than 14 kcal/mol for the Si-analogue.

The steric hindrance does become a problem, though, when t-butyl groups are placed on the Ge. Although the N can approach to within 2.67 Å in Fig 3d, the large deformation energy of 12.7 kcal/mol leads to an endothermic binding energy of +6.6 kcal/mol, a situation similar to that of its smaller FSiTb₃ cousin. The possibility of a second minimum, with longer R, was hence considered by a second optimization that began with R=3.0 Å, but this did not lead to a separate minimum.

The situation changes for the larger tetrel atoms Sn and Pb. Even when encumbered by three t-butyl substituents, there is still ample room for the approach of the base, leading to negative values of ΔE. NH₃ approaches to within 2.65 and 2.85 Å, respectively, for FSnTb₃ and FPbTb₃, as indicated in Figs 3e and 3f. Moreover, the deformation energies become progressively smaller, lowering from 12.7 kcal/mol for FGeTb₃, down to 6.4 for FSnTb₃, and as little as 2.9 kcal for the larger FPbTb₃. This reduction in the steric repulsion also enables the binding energy to become progressively more exothermic, -3.4 and -4.8 kcal/mol for these two complexes, respectively. In terms of the interaction energy between pre-distorted monomers in the last column of Table 3, it is the intermediate FSnTb₃ which forms the strongest native bond of -9.8 kcal/mol, although Ge and Pb are not far behind. It is noted finally that perusal of the data in the penultimate columns of Tables 1 and 3 demonstrates that the NH₃ base undergoes very little distortion as it approaches any of the Lewis acids, as it is
the latter that must distort to accommodate the base. The possibility of a second minimum with a longer value of \( R \) was considered in both cases, with none found.

### 3.2.1 Analysis of Wave Functions

The intensity and locations of the sigma holes in these heavier tetrel Lewis acids reflect some of the trends witnessed in the energetics. As the three H atoms of FGe\( \text{H}_3 \) are replaced by methyl, isopropyl, and then t-butyl groups, there is a steady erosion of the magnitude of \( V_{s,\text{max}} \), as may be seen in Table 4. As occurred in the tri-isopropyl Si monomer, the maximum in the MEP moves some distance away from the tetrel atom in FGe\( \text{Tb}_3 \), longer than 3 Å, which is in part responsible for its particularly small magnitude of only 13.9 kcal/mol. The dropping value of \( V_{s,\text{max}} \) as the substituent is enlarged is associated with the generally diminishing binding and interaction energies although the latter energetic patterns are disrupted for the trimethyl derivative. The enlargement of the tetrel atom from Ge to Sn to Pb intensifies the \( \sigma \)-hole without pulling it any further away from the tetrel atom. This trend conforms to \( \Delta E \) but not to \( E_{\text{int}} \).

AIM and NBO analyses can again offer insights into the sources of bonding in these complexes. The electron density at the Ge··\( \cdot \)N bond critical point is lowest for the methyl and isopropyl derivatives. This trend is consistent with \( E_{\text{int}} \), although not with \( \Delta E \) which must contend with monomer deformation energies. This same quantity is unaffected by the transition from Ge to Sn but is diminished for Pb, a trend which does not mirror either of the energetic parameters. Note that as in the Si cases in Table 2, there are several subsidiary bond paths involving the N atom which augment T··\( \cdot \)N to some degree. For example, all of the complexes involving \( \text{Tb}_3 \) species show evidence of one or more CH··\( \cdot \)N HBs.

Like the AIM values of \( \rho_{\text{BCP}} \), the Ge-F values of \( E(2) \) are smallest for FGe\( \text{Me}_3 \) and FGe\( \text{Iso}_3 \). NBO suggests a number of other interactions as well. Most surprising of these is the set of three GeH··\( \cdot \)N HBs in the FGe\( \text{H}_3 \) case, which are not verified by AIM. For the larger substituents, one sees charge transfer into all three \( \sigma^*(\text{Ge-C}) \) antibonding orbitals, an interaction which differs from the simpler CH··\( \cdot \)N HBs indicated by AIM. Enlargement of the tetrel atom induces a small but steady drop in the \( N_{\text{lp}} \rightarrow \sigma^*(\text{T-F}) \) \( E(2) \), which is not mirrored by the energetics. As in the Ge analogue, the \( \text{Tb}_3 \) derivatives of Sn and Pb show substantial charge transfer into the \( \sigma^*(\text{T-C}) \) orbitals which are not well aligned for such a transfer. Nonetheless, the particularly large such transfers for FSn\( \text{Tb}_3 \) may be responsible for the large magnitude of \( E_{\text{int}} \) for its complex with \( \text{NH}_3 \).

As in the case with the Si-containing systems, there is again a stretch in the T-F bond caused by charge transfer into its antibonding orbital. As may be seen in the last column of Table 4, these stretches vary between 0.022 Å for FGe\( \text{Iso}_3 \) up to a maximum of 0.049 Å for FPb\( \text{Tb}_3 \). Comparison with the stretches for the Si systems in Table 2 suggests that these elongations are larger for the heavier tetrel atoms, when compared to the actual energetics.
3.3 Correlations between Properties

One might anticipate there to be some connection between the various metrics that arise from analysis of the wave functions and the geometries and energetics of these complexes. For example, the stretching of the T-F bond ought to increase as more charge is transferred into the $\sigma^*(T-F)$ antibonding orbital. The correlation between these two quantities is modest, with a correlation coefficient of 0.88, as indicated in the first row of Table 5. The same charge transfer should have a direct influence upon the interaction energy, but their correlation coefficient is only a poor 0.56. On the other hand, it was shown above that there is a good deal of charge that is transferred into other antibonding orbitals of the Lewis acid. When all of these contributions in Tables 2 and 4 are summed, this total $E(2)$ correlates much better with the interaction energy, with $R^2=0.89$. Excellent prediction of the interaction energy is also achieved when considering the density at the T··N bond critical point, with a correlation coefficient of 0.88. Due to the differing sizes of the four T atoms, one would expect only a rough correlation between the interaction energy and $R(T··N)$. And indeed, the correlation coefficient for this pair of parameters is only 0.75. The importance of due consideration of steric crowding is evident in the last two rows of Table 5. When the binding energy $\Delta E$, prior to corrections for monomer deformation, is used in place of the interaction energy, these correlations deteriorate. For example, the correlation coefficient involving $\rho_{BCP}$ drops from 0.88 to 0.47. Likewise for the total NBO term, which sees a deterioration from 0.89 to 0.49.

3.4 Bulkier Lewis Base

As it is clear that a small base like NH$_3$ changes its geometry very little as it approaches even the bulkiest of the Lewis acids, it is natural to wonder how enlarging the base might affect its ability to engage in tetrel bonding. The three H atoms of NH$_3$ were thus enlarged to methyl groups and allowed to interact with three of the more crowded Lewis acids. FGe$\text{Iso}_3$ was the largest Ge-acid for which $\Delta E$ was negative (see Table 3) when interacting with NH$_3$. The enlargement of the base elongated the equilibrium $R(Ge··N)$ distance by 0.2 Å from 2.823 to 3.027 Å. On the other hand, the more basic character of NMe$_3$ also raised the binding energy a bit, from -3.64 to -6.22 kcal/mol. The longer intermolecular separation reduces the deformation energy slightly, to 1.74 kcal/mol. The interaction energy within the complex then is equal to -7.96 kcal/mol for NMe$_3$, slightly greater than the -6.02 kcal/mol for the smaller NH$_3$. The stronger interaction with the larger base occurs despite a less negative $V_{s,\text{min}}$ in the N lone pair area: -34.46 kcal/mol for NMe$_3$, vs -40.16 kcal/mol for NH$_3$. Also NMe$_3$ has a dipole moment only half that of NH$_3$, which ought to reduce the electrostatic attraction in the complex involving the larger base. So although stretching the $R(Ge··N)$ separation, the enlarged base is still able to engage in a thermodynamically viable tetrel bond, slightly stronger, even if longer, than that noted for NH$_3$.

The combination of $t$-butyl groups with the methyl groups on the base leads to complications in identifying truly tetrel-bonded complexes. The results of geometry optimization become highly dependent upon the
structures chosen for the individual monomers. Some optimizations led to minima on the surface, but these were quite shallow, and not necessarily of low energy. In the case of FPbTb₃, for example, two minima were located, one with R(Pb·N)=2.80 Å, and another longer distance of 3.380 Å. However, both of these minima were higher in energy than the sum of isolated monomers, with positive ∆E. Even after correction of ∆E by the monomer deformation energies, the resulting interaction energies remained positive. In these cases, then, one may infer that while the formation of tetrel bonds between these highly sterically hindered monomers may be possible in principle, each monomer must be able to rearrange from their optimal geometry before such an association can occur.

3.5 Anionic Bases

One would expect that placing a negative charge on the Lewis base would amplify the attractive force, and so might better compete against any steric repulsive forces. The fluoride ion is also small enough that steric repulsions should be minimized. And indeed, when F⁻ was permitted to interact with FSiMe₃, it approached the Si atom to within 1.828 Å, almost as short as the Si-F bond within the monomer. The formation of this trigonal bipyramid structure is exothermic by 40.57 kcal/mol. This situation is clearly quite distinct from the complex of this same Lewis acid with the neutral NH₃, where the R(Si··N) distance is 3.753 Å, and the binding energy is only 2.2 kcal/mol. The situation is much the same for the bulkier FSiIso₃, which also forms a trigonal bipyramid complex with F⁻, with R(Si··F)=1.830 Å, and ∆E=-44.76 kcal/mol. Again, the small fluoride is able to evade the steric repulsions which had plagued the complex with the neutral base, leading the latter to positive values of ∆E. The FGeTb₃ acid had also suffered from steric constraints when combined with NH₃, resulting in a positive ∆E. Replacement of the neutral base by F⁻ fully relieves these issues, leading to a trigonal bipyramid structure, and with ∆E=-54.16 kcal/mol.

Enlargement of the anion to Br⁻ reduces the binding energy relative to F⁻, but still avoids steric restrictions, and permits formation of a tetrel-bonded complex. When combined with FSiIso₃, the bromide approaches to within 3.143 Å of Si, and ∆E=-13.88 kcal/mol. The FGeTb₃ acid had its steric constraints relieved by F⁻. Replacement of NH₃ by the larger Br⁻ anion again relieves the repulsive forces, allowing this anion to approach the Ge atom to within 3.015 Å, and yielding a healthy -9.58 kcal/mol for ∆E. In summary, then, the enhanced attractive force engendered by anions is sufficient to overcome steric issues which limit the tetrel bonding of neutral bases.

4. SUMMARY AND DISCUSSION

In summary, FSiR₃ displays some evidence of steric hindrance to the formation of a tetrel bond with NH₃ when the R is either isopropyl or t-butyl. While the N can approach to within about 2.5 Å of the Si atom, the binding energy is positive, due to deformations that occur within the Lewis acid to accommodate the incoming base. Even with smaller R=Me groups, steric forces are present that push the base out to a longer distance. The
incorporation of electron-withdrawing halogen atoms as substituents on Si act to pull the NH$_3$ in rather close, and thereby engender a good deal of monomer geometry deformation. But even so, the binding energy is negative. Larger tetrel atoms are less electronegative and more polarizable, so exert a stronger pull on the base. These FTR$_3$ molecules also appear more flexible, and better able to distort to allow the base to approach. The binding energy of FGeR$_3$ is negative even for the isopropyl R but becomes positive for t-butyl. Both the Sn and Pb analogues can fully accommodate NH$_3$ with a negative $\Delta E$ and small R(T·N) even for the bulky t-butyl group. Further stress is placed on the tetrel bonds when the larger NMe$_3$ base is considered.

In any set of quantum calculations, there is always some question as to the accuracy of the particular level of theory that has been chosen. For example, the next size larger basis set would be the triple-valence aug-cc-pVTZ set (and corresponding aug-cc-pVTZ-PP for Sn and Pb). In past studies of similar sorts of noncovalent bonds, this expansion of basis set typically leads to a small increase in the interaction energy. As shown in Table 6, these tetrel bonds are no exception. The rise in this quantity ranges from less than 1 kcal/mol to as much as 5 kcal/mol for the most strongly bound. On a percentage basis, this increase is more uniform, between 10 and 28%. Most importantly, the expansion of the basis set does not alter any of the trends encountered with aug-cc-pVDZ. Moreover, a good deal of past work has verified the strengthening of the interaction with the larger set, but more importantly, that the improvement of the correlation method from MP2 to CCSD(T), including extrapolation to a complete basis set, reverses this effect, leaving MP2/aug-cc-pVDZ data quite similar to the gold standard CCSD(T)/CBS values.

A note of caution should be exercised in the search for minima in complexes such as these. In the case of the complexation of NH$_3$ with FSiIso$_3$, for example, there are two separate minima. The more stable of the two occurs for an intermolecular separation of 3.1 Å, considerably longer than most tetrel bonds. If the two monomers are able to overcome an energy barrier as they continue to approach one another more closely, they reach a second minimum, with R=2.5 Å and a legitimate tetrel bond. While this second minimum is less stable than the first by some 6.6 kcal/mol, this energy rise, along with the energy barrier separating the two minima, is due largely to internal deformation energy within the monomers. Consequently, the interaction energy between the two monomers, in their pre-deformed geometries, is -7.4 kcal/mol for the complex with the shorter intermolecular distance, as compared to only -2.3 kcal/mol for the outer-sphere complex.

Possible manifestations of short and long-range minima can be quite varied, depending upon the nature of the tetrel atom. As indicated above, when three bulky isopropyl substituents are added to Si, both of these minima occur, both with positive values of $\Delta E$, and negative interaction energies. Replacement with the slightly bulkier tert-butyl groups removes the second, outer-sphere minimum. The sole remaining minimum has a very positive $\Delta E$, but negative interaction energy between pre-distorted monomers. Enlargement of the tetrel atom to Ge eliminates the long-range minimum for both the isopropyl and t-butyl-substituted monomer. The
tetrel-bonded structure for the former has a negative ΔE, but the enlarged monomer deformation energy leads to a positive ΔE for the latter (with very similar interaction energies for the two).

There thus appears to be a clear and systematic trend that enlarging the tetrel atom reduces the consequences of steric crowding. Considering those Lewis acids with three t-butyl substituents, a tetrel bond can be formed for Si, but with a very positive ΔE, which remains positive for Ge. Both Sn and Pb allow negative binding energies to emerge. The progressive relaxation of steric repulsions is clear in the lowering distortion energies: 15.0, 12.7, 6.4, and 2.9 kcal/mol respectively for Si, Ge, Sn, and Pb. With these deformations accounted for, the remaining interaction energies within these same complexes are -4.9, -6.1, -9.8, and -7.7 kcal/mol. As indicated above, the addition of electron-releasing methyl substituents on the Lewis base adds to the binding energy of FGeISO₃, as well as the interaction energy, even though the added steric repulsions of the new methyl groups stretch the tetrel bond by some 0.2 Å. The combination of this larger NMe₃ base with t-butyl groups on the acid leads to real complications in bringing the two molecules together.

The situation can be further complicated by multiple minima for the monomers themselves. Again using the FSiISO₃ system as an example, there are a number of orientations of the three isopropyl groups that can be envisioned. The particular arrangement that is most stable in the case of the monomer is not necessarily the same as the global minimum for the complex with NH₃. In this particular case, the global minimum for the monomer lies some 1.5 kcal/mol lower than the geometry that corresponds to the most stable dimer. Failure of the isopropyl groups of the monomer to rearrange in preparation for complexation, which would need to overcome an energy barrier in addition to an overall less stable monomer, results in a complex that is 4.8 kcal/mol less stable than the global minimum of the dimer.

The examination of the MEP of the Lewis acid monomer, and its sensitivity to its conformation, brings up another issue related to the steric crowding involved in tetrel bonds. As the base approaches, there is a substantial change in the acid’s geometry. If instead of computing the MEP of the undistorted monomer, one instead considers the potential of the monomer within the context of the dimer, distorted to permit its complexation with NH₃, the data can be quite different. Taking the FSiISO₃·NH₃ dimer as a prime example, in the case of the outer-sphere complex, with R(Si·N)=3.09 Å, $V_{s,max}$ is located only 1.99 Å from the Si atom, and is enlarged from 21.99 to 38.04 kcal/mol. The distinction is even more dramatic for the tetrel-bonded structure b, with R=2.50 Å. Adjusting the FSiISO₃ monomer to its geometry within this complex brings the $V_{s,max}$ point in from 3.02 to 1.91 Å, and raises the density at this point by five-fold, to 49.28 kcal/mol. This issue is not restricted to only FSiISO₃·NH₃ which is characterized by two separate minima. Even in the single minimum of FSiTb₃·NH, the change of geometry of FSiTb₃ from its optimized structure to that within the dimer raises $V_{s,max}$ from 11.14 to 49.89 kcal/mol and draws this point in from 3.22 to only 1.92 Å from the Si nucleus. So while inspection of the MEP is of course a valuable tool in understanding the nature and strength of tetrel bonds, it is
important to be wary of complications that arise in terms of which specific geometry is to be considered. This issue may not be restricted purely to tetrel bonds, as it has arisen previously in the context of certain pnictogen bonds.

There are a few prior results that offer points of comparison. An early spectral measurement of the tetrel bond length of 2.09 Å in FSiF₃···NH₃ is consistent with the distances of the related complexes in Table 1, and also confirms significant monomer geometric distortions. A study of the dimer of Me₅SnCN at various levels of calculation found interaction energies for the Sn···N tetrel bond that are comparable to that computed here. The stronger tetrel bonds formed by NMe₃ vs NH₃ was verified, as was the superiority of Pb and Sn over Ge and Si, and several studies confirm the enhanced strength when an anionic base is included. Grabowski had recently considered the tetrel bonding of SnF₄ and PbF₄ with N bases, and obtained data consistent with our own findings that significant deformation energies accompany the binding of these perhalogenated Lewis acids. The magnitudes of these distortion energies are smaller than those obtained here for FSiX₃, consistent with the lesser distortions required to bind to the larger Sn and Pb atoms. This author also scanned available crystal structures and identified certain geometries with this tetrel-bonded Sn motif. A recent calculation of FGeH₃···NH₃ with a larger basis set yielded nearly identical binding and interaction energies as our own data in Table 3.

In a more general sense, the various forces involved in noncovalent, and indeed other bonds as well, derive from Coulombic forces involving nuclei and electrons, coupled with issues related to electron spin. Various components of the intermolecular forces, such as electrostatic, polarization, steric repulsions, and charge transfer all fall within this overall umbrella. One can also argue that charge transfer is a form of polarization. Nonetheless, a separation into these various terms offers a solid and physically sound conceptual basis on which to better understand the nature of intermolecular forces, which have motivated countless analyses of this type.

In conclusion, tetrel bonding can be quite strong, with interaction energies exceeding 35 kcal/mol for a pair of neutral molecules, and up to 54 kcal/mol for an anionic base. Even when all substituents are nonpolar alkyl groups, the interaction energy can reach 10 kcal/mol. However, steric crowding is an issue that must be thoughtfully considered in the context of tetrel bonding. This issue becomes progressively more important as the substituents on the two molecules are enlarged. Its effects can be partially assuaged if the attractive force is particularly large, as for example for anionic bases, or for highly electron-withdrawing substituents on the Lewis acid. But even in such cases, there may be a high degree of monomer deformation which must be overcome in order for this bond to occur.
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Table 1. Equilibrium R(Si···N) intermolecular distance in complexes of FSiR₃ with NH₃. Interaction energies of dimers, and deformation energies induced in monomers in order to form dimer. Energies in kcal/mol.

<table>
<thead>
<tr>
<th>FSiR₃</th>
<th>R, Å</th>
<th>∆E</th>
<th>E_{def}(LA)</th>
<th>E_{def}(LB)</th>
<th>E_{int} = ∆E - E_{def}</th>
</tr>
</thead>
<tbody>
<tr>
<td>FSiH₃</td>
<td>2.557</td>
<td>-5.49</td>
<td>1.93</td>
<td>0.00</td>
<td>-7.42</td>
</tr>
<tr>
<td>FSiMe₃</td>
<td>3.753</td>
<td>-2.24</td>
<td>0.12</td>
<td>0.01</td>
<td>-2.37</td>
</tr>
<tr>
<td>FSiMe₂(CF₃)₁</td>
<td>2.392</td>
<td>-2.11</td>
<td>11.02</td>
<td>0.02</td>
<td>-13.15</td>
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<td>FSiMe₁(CF₃)₂</td>
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<td>-9.22</td>
<td>15.70</td>
<td>0.05</td>
<td>-24.97</td>
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<td>FSi(CF₃)₃</td>
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<td>-18.20</td>
<td>17.29</td>
<td>0.06</td>
<td>-35.55</td>
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<td>FSiSO₃ a</td>
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<td>2.48</td>
<td>0.02</td>
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<td></td>
<td>2.499</td>
<td>+6.80</td>
<td>14.16</td>
<td>0.00</td>
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<td>FSiSO₂(CF₃)₁</td>
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<td>10.26</td>
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<td>FSiTb</td>
<td>2.519</td>
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<td>FSiCl₃</td>
<td>2.068</td>
<td>-5.45</td>
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<td>-25.34</td>
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<td>FSiBr₃</td>
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<td>-4.73</td>
<td>17.70</td>
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<td>-3.31</td>
<td>14.57</td>
<td>0.21</td>
<td>-18.09</td>
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a primarily stabilized by CH···N
Table 2. Maximum electrostatic potential on isodensity surface of $\text{FSiR}_3$, density at Si··N bond critical point and NBO charge transfer energy from N lone pair (or SiN bonding orbital) to indicated antibonding orbital in Lewis acid.

<table>
<thead>
<tr>
<th>$\text{FSiR}_3$</th>
<th>$V_{s,\text{max}}$</th>
<th>$R(\text{Si}··V_{s,\text{max}})$</th>
<th>$\rho_{\text{BCP}}$</th>
<th>$\text{NBO E}(2)$</th>
<th>$\Delta r(\text{Si-F})$</th>
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</thead>
<tbody>
<tr>
<td></td>
<td>kcal/mol</td>
<td>Å</td>
<td>au</td>
<td>kcal/mol</td>
<td>Å</td>
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<tr>
<td>$\text{FSiH}_3$</td>
<td>41.016</td>
<td>1.940</td>
<td>0.0233</td>
<td>17.97(Si-F)</td>
<td>0.026</td>
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<td></td>
<td>3.90(3Si-H)</td>
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<tr>
<td>$\text{FSiMe}_3$</td>
<td>26.919</td>
<td>2.134</td>
<td>0.0056 (3H$^a$)</td>
<td>1.30(Si-F)</td>
<td>0.005</td>
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<td></td>
<td>0.57(3C-H)</td>
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<td>$\text{FSiMe}_2(\text{CF}_3)_1$</td>
<td>31.713</td>
<td>2.178</td>
<td>0.0325 0.0121(1F$^b$)</td>
<td>18.31(Si-F)</td>
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<td>11.10(Si-CF$_3$)</td>
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<td>7.43(2Si-CH$_3$)</td>
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<td>2.19(C-F)</td>
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<td>2.41(C-F)</td>
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<td>$\text{FSi(CF}_3)_3$</td>
<td>42.369</td>
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<td>a 21.994 b 9.917</td>
<td>a 2.241 b 3.016</td>
<td>0.0095(3H$^a$) 0.0096(1C$^c$)</td>
<td>8.25(Si-F) 1.46(3Si-C)</td>
<td>0.011</td>
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<td>$\text{FSi(ISO}_2(\text{CF}_3)_3$</td>
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<td>19.67(Si-F)</td>
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<td>11.82(Si-CF$_3$)</td>
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<td>23.56(Si-F)</td>
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<tr>
<td>$\text{FSiBr}_3$</td>
<td>21.359</td>
<td>2.260</td>
<td>0.0601</td>
<td>20.11(Si-F)</td>
<td>0.035</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td>17.30(3Si-Br)</td>
<td></td>
</tr>
<tr>
<td>$\text{FSiI}_3$</td>
<td>14.140</td>
<td>2.414</td>
<td>0.0579</td>
<td>18.67(Si-F)</td>
<td>0.037</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td>15.12(3Si-I)</td>
<td></td>
</tr>
</tbody>
</table>

$^a$ bonds involving N and one H atom of each alkyl group

$^b$ bond involving N and one F atom of CF$_3$ group

$^c$ bond involving N and C atom of one alkyl group

$^d$ AIM and NBO data for complex a
Table 3. Equilibrium R(T·⋅N) intermolecular distance in complexes of FTR$_3$ with NH$_3$, T=Ge, Sn, Pb. Interaction energies of dimers, and deformation energies induced in monomers in order to form dimer. Energies in kcal/mol.

<table>
<thead>
<tr>
<th>FTR$_3$</th>
<th>R, Å</th>
<th>$\Delta E$</th>
<th>$E_{\text{def}}$(LA)</th>
<th>$E_{\text{def}}$(LB)</th>
<th>$E_{\text{int}}=\Delta E - E_{\text{def}}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>FGeH$_3$</td>
<td>2.627</td>
<td>-5.84</td>
<td>1.49</td>
<td>0.00</td>
<td>-7.33</td>
</tr>
<tr>
<td>FGeMe$_3$</td>
<td>2.775</td>
<td>-1.36</td>
<td>0.40</td>
<td>0.01</td>
<td>-1.77</td>
</tr>
<tr>
<td>FGeIso$_3$</td>
<td>2.823</td>
<td>-3.64</td>
<td>2.38</td>
<td>0.00</td>
<td>-6.02</td>
</tr>
<tr>
<td>FGeTb$_3$</td>
<td>2.670</td>
<td>+6.63</td>
<td>12.71</td>
<td>0.00</td>
<td>-6.08</td>
</tr>
<tr>
<td>FSnTb$_3$</td>
<td>2.653</td>
<td>-3.42</td>
<td>6.41</td>
<td>0.01</td>
<td>-9.84</td>
</tr>
<tr>
<td>FPbTb$_3$</td>
<td>2.851</td>
<td>-4.77</td>
<td>2.89</td>
<td>0.00</td>
<td>-7.66</td>
</tr>
</tbody>
</table>

Table 4. Maximum electrostatic potential on isodensity surface of FTR$_3$, density at T·⋅N bond critical point and NBO charge transfer energy from N lone pair to indicated antibonding orbital in Lewis acid.

<table>
<thead>
<tr>
<th>FTR$_3$</th>
<th>$V_{s,max}$ kcal/mol</th>
<th>R(T·⋅V$_{s,max}$) Å</th>
<th>$\rho_{\text{BCP}}$ au</th>
<th>NBO E(2) kcal/mol</th>
<th>$\Delta r$(T-F) Å</th>
</tr>
</thead>
<tbody>
<tr>
<td>FGeH$_3$</td>
<td>50.085</td>
<td>1.936</td>
<td>0.0236</td>
<td>17.58(Ge-F)</td>
<td>0.031</td>
</tr>
<tr>
<td>FGeMe$_3$</td>
<td>30.551</td>
<td>2.116</td>
<td>0.0179</td>
<td>14.04(Ge-F)</td>
<td>0.026</td>
</tr>
<tr>
<td>FGeIso$_3$</td>
<td>28.374</td>
<td>2.112</td>
<td>0.0166</td>
<td>16.16(Ge-F)</td>
<td>0.022</td>
</tr>
<tr>
<td>FGeTb$_3$</td>
<td>13.892</td>
<td>3.035</td>
<td>0.0288</td>
<td>21.39(Ge-F)</td>
<td>0.039</td>
</tr>
<tr>
<td>FSnTb$_3$</td>
<td>35.767</td>
<td>2.291</td>
<td>0.0291</td>
<td>20.94(Sn-F)</td>
<td>0.047</td>
</tr>
<tr>
<td>FPbTb$_3$</td>
<td>45.789</td>
<td>2.142</td>
<td>0.0229</td>
<td>19.28(Pb-F)</td>
<td>0.049</td>
</tr>
</tbody>
</table>

Table 5. Correlation coefficients between pairs of parameters

<table>
<thead>
<tr>
<th>$p_1$</th>
<th>$p_2$</th>
<th>$R^2$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\Delta r$(T-F)</td>
<td>E(2) N$_{lp}$→$\sigma^*(TF)$</td>
<td>0.882</td>
</tr>
<tr>
<td>$E_{\text{int}}$</td>
<td>E(2) N$_{lp}$→$\sigma^*(TF)$</td>
<td>0.564</td>
</tr>
<tr>
<td>$E_{\text{int}}$</td>
<td>E(2) total</td>
<td>0.893</td>
</tr>
<tr>
<td>$E_{\text{int}}$</td>
<td>$\rho_{\text{BCP}}$</td>
<td>0.877</td>
</tr>
<tr>
<td>$E_{\text{int}}$</td>
<td>R(T·⋅N)</td>
<td>0.751</td>
</tr>
<tr>
<td>$\Delta E$</td>
<td>$\rho_{\text{BCP}}$</td>
<td>0.471</td>
</tr>
<tr>
<td>$\Delta E$</td>
<td>E(2) total</td>
<td>0.489</td>
</tr>
</tbody>
</table>
Table 6. Interaction energies (kcal/mol) computed at MP2 level with two different basis sets for complexes with NH₃

<table>
<thead>
<tr>
<th>FTR₃</th>
<th>aug-cc-pVDZ</th>
<th>aug-cc-pVTZ</th>
</tr>
</thead>
<tbody>
<tr>
<td>FSiH₃</td>
<td>-7.42</td>
<td>-8.72</td>
</tr>
<tr>
<td>FSiMe₃</td>
<td>-2.37</td>
<td>-2.59</td>
</tr>
<tr>
<td>FSi(CF₃)₃</td>
<td>-35.55</td>
<td>-40.20</td>
</tr>
<tr>
<td>FSiCl₃</td>
<td>-25.34</td>
<td>-29.90</td>
</tr>
<tr>
<td>FSiBr₃</td>
<td>-22.61</td>
<td>-27.49</td>
</tr>
<tr>
<td>FSiI₃</td>
<td>-18.09</td>
<td>-23.20</td>
</tr>
<tr>
<td>FGeH₃</td>
<td>-7.33</td>
<td>-8.08</td>
</tr>
<tr>
<td>FGeMe₃</td>
<td>-1.77</td>
<td>-3.40</td>
</tr>
</tbody>
</table>
Fig 1. Geometries of indicated FSiR₃ Lewis acids with NH₃. Distances in Å.

Fig 2. Geometries of indicated FSiX₃ Lewis acids with NH₃. Distances in Å.
Fig 3. Geometries of indicated FTR₃ Lewis acids (T=Ge, Sn, Pb) with NH₃. Distances in Å.